# 74HC2G02-Q100; 74HCT2G02-Q100

**Dual 2-input NOR gate** 

Rev. 2 — 26 July 2018

**Product data sheet** 

### 1. General description

The 74HC2G02-Q100; 74HCT2G02-Q100 is a dual 2-input NOR gate. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of  $V_{\rm CC}$ .

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 2.0 V to 6.0 V
- Input levels:
  - For 74HC2G02-Q100: CMOS level
  - For 74HCT2G02-Q100: TTL level
- · Symmetrical output impedance
- · High noise immunity
- Complies with JEDEC standard no. 7A (4.5 V to 5.5 V)
- Low power dissipation
- · Balanced propagation delays
- Multiple package options
- ESD protection:
  - MIL-STD-883, method 3015 exceeds 2000 V
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0  $\Omega$ )

# 3. Ordering information

**Table 1. Ordering information** 

| Type number      | Package           |        |   |          |  |  |
|------------------|-------------------|--------|---|----------|--|--|
|                  | Temperature range | Name   | Description                                     | Version  |  |  |
| 74HC2G02DP-Q100  | -40 °C to +125 °C | TSSOP8 | process and comment and process go,             |          |  |  |
| 74HCT2G02DP-Q100 |                   |        | 8 leads; body width 3 mm; lead length 0.5 mm    |          |  |  |
| 74HC2G02DC-Q100  | -40 °C to +125 °C | VSSOP8 | plastic very thin shrink small outline package; | SOT765-1 |  |  |
| 74HCT2G02DC-Q100 |                   |        | 8 leads; body width 2.3 mm                      |          |  |  |



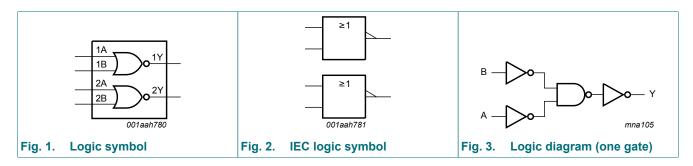
# 4. Marking

### Table 2. Marking code

| Type number      | Marking code [1] |
|------------------|------------------|
| 74HC2G02DP-Q100  | H02              |
| 74HCT2G02DP-Q100 | T02              |
| 74HC2G02DC-Q100  | H02              |
| 74HCT2G02DC-Q100 | T02              |

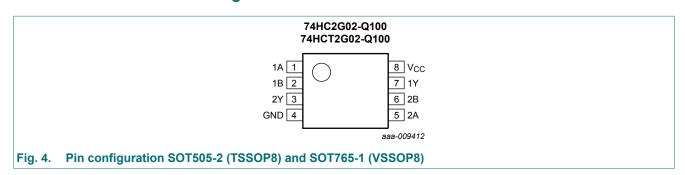
<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

# 5. Functional diagram



# 6. Pinning information

### 6.1. Pinning



### 6.2. Pin description

Table 3. Pin description

| Symbol          | Pin  | Description    |
|-----------------|------|----------------|
| 1A, 2A          | 1, 5 | data input     |
| 1B, 2B          | 2, 6 | data input     |
| GND             | 4    | ground (0 V)   |
| 1Y, 2Y          | 7, 3 | data output    |
| V <sub>CC</sub> | 8    | supply voltage |

### 7. Functional description

#### **Table 4. Function table**

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$ 

| Input |    | Output |
|-------|----|--------|
| nA    | nB | nY     |
| L     | L  | Н      |
| L     | Н  | L      |
| Н     | L  | L      |
| Н     | Н  | L      |

# 8. Limiting values

#### **Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter                 | Conditions  | Min  | Max  | Unit |
|------------------|---------------------------|---|------|------|------|
| $V_{CC}$         | supply voltage            |   | -0.5 | +7.0 | V    |
| I <sub>IK</sub>  | input clamping current    | $V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$ [1]   | -    | ±20  | mA   |
| I <sub>OK</sub>  | output clamping current   | $V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$ [1]       | -    | ±20  | mA   |
| Io               | output current            | $V_{\rm O} = -0.5 \text{ V to } (V_{\rm CC} + 0.5 \text{ V})$ [1] | -    | 25   | mA   |
| I <sub>CC</sub>  | supply current            | [1]   | -    | 50   | mA   |
| $I_{GND}$        | ground current            | [1]   | -50  | -    | mA   |
| T <sub>stg</sub> | storage temperature       |   | -65  | +150 | °C   |
| $P_D$            | dynamic power dissipation | $T_{amb} = -40  ^{\circ}\text{C to } +125  ^{\circ}\text{C}$ [2]  | -    | 300  | mW   |

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

# 9. Recommended operating conditions

### Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter           | Conditions              | 74HC2G02-Q100 |      | 74HCT2G02-Q100  |     |      | Unit            |      |
|------------------|---------------------|-------------------------|---------------|------|-----------------|-----|------|-----------------|------|
|                  |                     |                         | Min           | Тур  | Max             | Min | Тур  | Max             |      |
| V <sub>CC</sub>  | supply voltage      |                         | 2.0           | 5.0  | 6.0             | 4.5 | 5.0  | 5.5             | V    |
| VI               | input voltage       |                         | 0             | -    | V <sub>CC</sub> | 0   | -    | V <sub>CC</sub> | V    |
| Vo               | output voltage      |                         | 0             | -    | V <sub>CC</sub> | 0   | -    | V <sub>CC</sub> | V    |
| T <sub>amb</sub> | ambient temperature |                         | -40           | +25  | +125            | -40 | +25  | +125            | °C   |
| Δt/ΔV            | input transition    | V <sub>CC</sub> = 2.0 V | -             | -    | 625             | -   | -    | -               | ns/V |
|                  | rise and fall rate  | V <sub>CC</sub> = 4.5 V | -             | 1.67 | 139             | -   | 1.67 | 139             | ns/V |
|                  |                     | V <sub>CC</sub> = 6.0 V | -             | -    | 83              | -   | -    | -               | ns/V |

<sup>[2]</sup> For TSSOP8 package: above 55 °C the value of P<sub>tot</sub> derates linearly with 2.5 mW/K. For VSSOP8 package: above 110 °C the value of P<sub>tot</sub> derates linearly with 8 mW/K.

# 10. Static characteristics

### **Table 7. Static characteristics**

Voltages are referenced to GND (ground = 0 V).

| Symbol Parameter                        |                          | Conditions  | -4   | -40 °C to +85 °C |      |      | -40 °C to +125 °C |    |
|---|--------------------------|---|------|------------------|------|------|-------------------|----|
|   |                          |   | Min  | Typ [1]          | Max  | Min  | Max               |    |
| 74HC2G                                  | 02-Q100                  |   |      |                  |      |      |                   |    |
| V <sub>IH</sub>                         | HIGH-level input         | V <sub>CC</sub> = 2.0 V   | 1.5  | 1.2              | -    | 1.5  | -                 | V  |
|   | voltage                  | V <sub>CC</sub> = 4.5 V   | 3.15 | 2.4              | -    | 3.15 | -                 | V  |
|   |                          | V <sub>CC</sub> = 6.0 V   | 4.2  | 3.2              | -    | 4.2  | -                 | V  |
| V <sub>IL</sub>                         | LOW-level input          | V <sub>CC</sub> = 2.0 V   | -    | 0.8              | 0.5  | -    | 0.5               | V  |
|   | voltage                  | V <sub>CC</sub> = 4.5 V   | -    | 2.1              | 1.35 | -    | 1.35              | V  |
|   |                          | V <sub>CC</sub> = 6.0 V   | -    | 2.8              | 1.8  | -    | 1.8               | V  |
| V <sub>OH</sub>                         | HIGH-level output        | $V_I = V_{IH}$ or $V_{IL}$  |      |                  |      |      |                   |    |
|   | voltage                  | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V                    | 1.9  | 2.0              | -    | 1.9  | -                 | V  |
|   |                          | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V                    | 4.4  | 4.5              | -    | 4.4  | -                 | V  |
|   |                          | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V                    | 5.9  | 6.0              | -    | 5.9  | -                 | V  |
|   |                          | $I_{O}$ = -4.0 mA; $V_{CC}$ = 4.5 V                                 | 4.13 | 4.32             | -    | 3.7  | -                 | V  |
|   |                          | $I_{O}$ = -5.2 mA; $V_{CC}$ = 6.0 V                                 | 5.63 | 5.81             | -    | 5.2  | -                 | V  |
| V <sub>OL</sub>                         | LOW-level output         | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>                 |      |                  |      |      |                   |    |
|   | voltage                  | $I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 2.0 $V$                            | -    | 0                | 0.1  | -    | 0.1               | V  |
|   |                          | $I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 4.5 $V$                            | -    | 0                | 0.1  | -    | 0.1               | V  |
|   |                          | $I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 6.0 $V$                            | -    | 0                | 0.1  | -    | 0.1               | V  |
|   |                          | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V                    | -    | 0.15             | 0.33 | -    | 0.4               | V  |
|   |                          | I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 6.0 V                    | -    | 0.16             | 0.33 | -    | 0.4               | V  |
| I <sub>I</sub>                          | input leakage current    | $V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$                     | -    | -                | ±1.0 | -    | ±1.0              | μΑ |
| I <sub>CC</sub>                         | supply current           | per input pin; $V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0$ V | -    | -                | 10   | -    | 20                | μΑ |
| Cı                                      | input capacitance        |   | -    | 1.5              | -    | -    | -                 | pF |
| <b>74HCT2</b>                           | G02-Q100                 |   |      | •                | 1    |      |                   |    |
| V <sub>IH</sub>                         | HIGH-level input voltage | V <sub>CC</sub> = 4.5 V to 5.5 V                                    | 2.0  | 1.6              | -    | 2.0  | -                 | V  |
| V <sub>IL</sub> LOW-level input voltage |                          | V <sub>CC</sub> = 4.5 V to 5.5 V                                    | -    | 1.2              | 8.0  | -    | 0.8               | V  |
|   |                          | $V_I = V_{IH}$ or $V_{IL}$  |      |                  |      |      |                   |    |
|   | voltage                  | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V                    | 4.4  | 4.5              | -    | 4.4  | -                 | V  |
|   |                          | $I_{O}$ = -4.0 mA; $V_{CC}$ = 4.5 V                                 | 4.13 | 4.32             | -    | 3.7  | -                 | V  |
| V <sub>OL</sub>                         | LOW-level output         | $V_I = V_{IH}$ or $V_{IL}$  |      |                  |      |      |                   |    |
|   | voltage                  | $I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 4.5 $V$                            | -    | 0                | 0.1  | -    | 0.1               | V  |
|   |                          | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V                    | -    | 0.15             | 0.33 | -    | 0.4               | V  |

| Symbol           | Parameter                 | r Conditions  |     | -40 °C to +85 °C |      |     | -40 °C to +125 °C |    |  |
|------------------|---------------------------|---|-----|------------------|------|-----|-------------------|----|--|
|                  |                           |   | Min | Typ [1]          | Max  | Min | Max               |    |  |
| II               | input leakage<br>current  | $V_1 = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$   | -   | -                | ±1.0 | -   | ±1.0              | μΑ |  |
| I <sub>CC</sub>  | supply current            | $V_I = V_{CC}$ or GND; $I_O = 0$ A;<br>$V_{CC} = 5.5 \text{ V}$   | -   | -                | 10   | -   | 20                | μΑ |  |
| Δl <sub>CC</sub> | additional supply current | per input; $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V};$<br>$V_I = V_{CC} - 2.1 \text{ V}; I_O = 0 \text{ A}$ | -   | -                | 375  | -   | 410               | μΑ |  |
| Cı               | input capacitance         |   | -   | 1.5              | -    | -   | -                 | pF |  |

<sup>[1]</sup> All typical values are measured at  $T_{amb}$  = 25 °C.

# 11. Dynamic characteristics

### **Table 8. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit, see Fig. 6.

| Symbol          | Parameter                     | Conditions                                      |     | -40 | °C to +85 | °C  | -40 °C to | +125 °C | Unit |
|-----------------|-------------------------------|---|-----|-----|-----------|-----|-----------|---------|------|
|                 |                               |   |     | Min | Typ [1]   | Max | Min       | Max     |      |
| 74HC2G          | 02-Q100                       |   |     |     |           |     |           |         |      |
| t <sub>pd</sub> | propagation delay             | nA and nB to nY; see Fig. 5                     | [2] |     |           |     |           |         |      |
|                 |                               | V <sub>CC</sub> = 2.0 V                         |     | -   | 26        | 95  | -         | 110     | ns   |
|                 |                               | V <sub>CC</sub> = 4.5 V                         |     | -   | 9         | 19  | -         | 22      | ns   |
|                 |                               | V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF |     | -   | 9         | -   | -         | -       | ns   |
|                 |                               | V <sub>CC</sub> = 6.0 V                         |     | -   | 8         | 16  | -         | 20      | ns   |
| t <sub>t</sub>  | transition time               | see Fig. 5                                      | [3] |     |           |     |           |         |      |
|                 |                               | V <sub>CC</sub> = 2.0 V                         |     | -   | 19        | 95  | -         | 125     | ns   |
|                 |                               | V <sub>CC</sub> = 4.5 V                         |     | -   | 7         | 19  | -         | 25      | ns   |
|                 |                               | V <sub>CC</sub> = 6.0 V                         |     | -   | 5         | 16  | -         | 20      | ns   |
| C <sub>PD</sub> | power dissipation capacitance | $V_I = GND \text{ to } V_{CC}$                  | [4] | -   | 10        | -   | -         | -       | pF   |
| <b>74HCT2</b>   | G02-Q100                      |   | '   |     |           |     |           | '       |      |
| t <sub>pd</sub> | propagation delay             | nA and nB to nY; see Fig. 5                     | [2] |     |           |     |           |         |      |
|                 |                               | V <sub>CC</sub> = 4.5 V                         |     | -   | 12        | 24  | -         | 29      | ns   |
|                 |                               | V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF |     | -   | 12        | -   | -         | -       | ns   |
| t <sub>t</sub>  | transition time               | V <sub>CC</sub> = 4.5 V; see <u>Fig. 5</u>      | [3] | -   | 6         | 19  | -         | 22      | ns   |
| C <sub>PD</sub> | power dissipation capacitance | $V_{\rm I}$ = GND to $V_{\rm CC}$ - 1.5 V [4]   |     | -   | 10        | -   | -         | -       | pF   |

- [1] All typical values are measured at  $T_{amb}$  = 25 °C.
- [2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .
- [3]  $t_t$  is the same as  $t_{TLH}$  and  $t_{THL}$ .
- [4]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

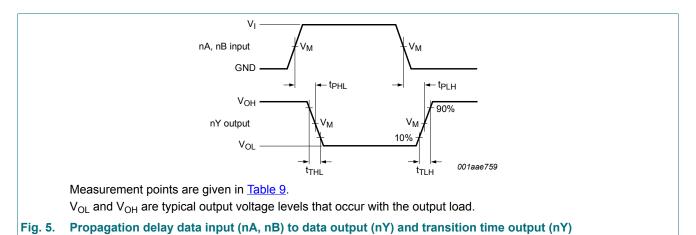
C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

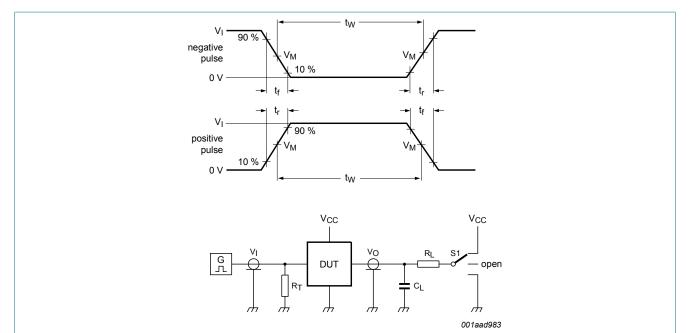
 $\Sigma(C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs.}$ 

### 11.1. Waveforms and test circuit



**Table 9. Measurement points** 

| Туре           | Input                 | Output                |
|----------------|-----------------------|-----------------------|
|                | V <sub>M</sub>        | V <sub>M</sub>        |
| 74HC2G02-Q100  | 0.5 × V <sub>CC</sub> | 0.5 × V <sub>CC</sub> |
| 74HCT2G02-Q100 | 1.3 V                 | 1.3 V                 |



Test data is given in Table 10.

Definitions for test circuit:

 $R_T$  = Termination resistance should be equal to output impedance  $Z_0$  of the pulse generator.

C<sub>L</sub> = Load capacitance including jig and probe capacitance.

R<sub>L</sub> = Load resistance.

S1 = Test selection switch.

### Fig. 6. Test circuit for measuring switching times

Table 10. Test data

| Туре           | Input L                |                                 | Load         | S1 position    |                                     |
|----------------|------------------------|---------------------------------|--------------|----------------|-------------------------------------|
|                | V <sub>I</sub>         | t <sub>r</sub> , t <sub>f</sub> | CL           | R <sub>L</sub> | t <sub>PHL</sub> , t <sub>PLH</sub> |
| 74HC2G02-Q100  | GND to V <sub>CC</sub> | ≤ 6 ns                          | 15 pF, 50 pF | 1 kΩ           | open                                |
| 74HCT2G02-Q100 | GND to 3 V             | ≤ 6 ns                          | 15 pF, 50 pF | 1 kΩ           | open                                |

# 12. Package outline

TSSOP8: plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm SOT505-2

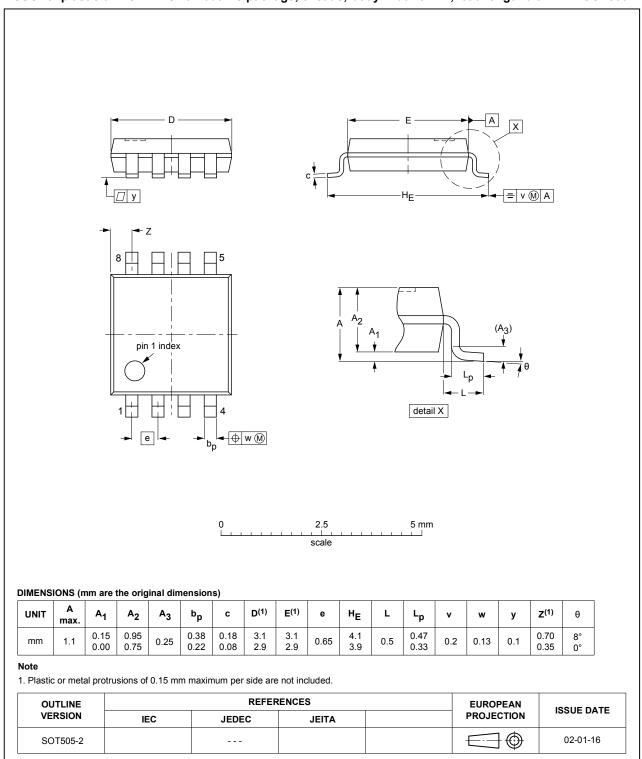


Fig. 7. Package outline SOT505-2 (TSSOP8)

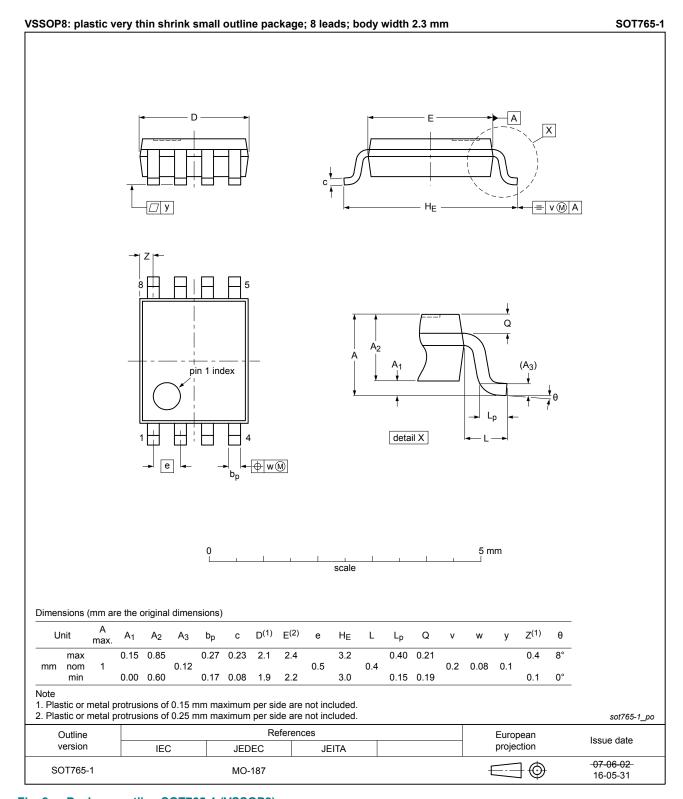


Fig. 8. Package outline SOT765-1 (VSSOP8)

# 13. Abbreviations

### **Table 11. Abbreviations**

| Acronym | Description                             |
|---------|---|
| CMOS    | Complementary Metal-Oxide Semiconductor |
| DUT     | Device Under Test                       |
| ESD     | ElectroStatic Discharge                 |
| НВМ     | Human Body Model                        |
| MIL     | Military                                |
| MM      | Machine Model                           |
| TTL     | Transistor-Transistor Logic             |

# 14. Revision history

### Table 12. Revision history

| Document ID           | Release date  | Data sheet status  | Change notice | Supersedes            |  |  |  |
|-----------------------|---|--------------------|---------------|-----------------------|--|--|--|
| 74HC_HCT2G02_Q100 v.2 | 20180726  | Product data sheet | -             | 74HC_HCT2G02_Q100 v.1 |  |  |  |
| Modifications:        | <ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul> |                    |               |                       |  |  |  |
| 74HC_HCT2G02_Q100 v.1 | 20131111  | Product data sheet | -             | -                     |  |  |  |

### 15. Legal information

#### **Data sheet status**

| Document status [1][2]         | Product<br>status [3] | Definition  |
|--------------------------------|-----------------------|---|
| Objective [short] data sheet   | Development           | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification         | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production            | This document contains the product specification.                                     |

- Please consult the most recently issued document before initiating or completing a design.
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